

Dual NPN-PNP complementary Bipolar transistor

Features

- Low VCE(sat)=0.5V (Typ.)
- Simplified circuit design
- Reduced component count

Applications

- Push-Pull or Totem-Pole configuration
- MOSFET and IGBT gate driving
- Motor, relay and solenoid driving

Description

The SUT290 is a Hybrid dual NPN-PNP complementary power bipolar transistor manufactured by using the latest low voltage planar technology. The SUT290 is housed in dual island SOP-8 package with separated terminals for higher assembly flexibility, specifically recommended to be used in Push-Pull or Totem Pole configuration as post IGBTs and MOSFETs driver.



Internal schematic diagram



Ordering Information

Type NO.	Marking	Package Code
SUT290	SUT290	SOP-8

Absolute Maximum Ratings

Characteristic	Symbol	Rating		Unit	
Characteristic	Symbol	Tr1	Tr2	Unit	
Collector-base voltage	V _{CBO}	40	-40	V	
Collector-emitter voltage	V _{CEO}	32	-32	V	
Emitter-base voltage	V _{EBO}	5	-5	V	
Collector current	Ι _C	2	-2	А	
Power discipation	D *	2		W/TOTAL	
rower dissipation	۲D	1.4		W/ELEMENT	
Junction temperature	TJ	15	50	٥C	
Storage temperature range	T _{stg}	-55~150		°C	

 $\ensuremath{\ensuremath{\mathbb{X}}}$: When mounted on 40x40x0.8 $\ensuremath{\mathsf{mm}}$ ceramic substrate

(Ta=25°C)

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Electrical Characteristics [Tr1]

Electrical Characteristics [Tr1] (Ta=25°C)					5°C)	
Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Collector-base breakdown voltage	BV _{CBO}	$I_{C}=50uA$, $I_{E}=0$	40	-	-	V
Collector-emitter breakdown voltage	BV _{CEO}	$I_{C}=1mA$, $I_{B}=0$	32	-	-	V
Emitter-base breakdown voltage	BV_{EBO}	$I_{c}=50uA, I_{c}=0$	5	-	-	V
Collector cut-off current	I _{CBO}	$V_{CB} = 20V, I_{E} = 0$	-	-	1	μA
Emitter cut-off current	I _{EBO}	V_{EB} =4V, I_{C} =0	-	-	1	μA
DC current gain	h _{FE}	$V_{CE} = 3V$, $I_{C} = 0.5A$	120	-	320	-
Collector-emitter saturation voltage	V _{CE(sat)}	I _C =2A, I _B =200mA	-	0.5	0.8	V
Transition frequency	f⊤	V_{CE} =5V, I_{C} =10mA	-	100	-	MHz
Collector output capacitance	C _{ob}	V_{CB} =10V, I_E =0, f=1MHz	-	30	-	pF

Electrical Characteristics [Tr2]

Electrical Characteristics [Tr2] (Ta=25°C					5°C)	
Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Collector-base breakdown voltage	BV _{CBO}	I_{C} =-50uA, I_{E} =0	-40	-	-	V
Collector-emitter breakdown voltage	BV _{CEO}	I_{C} =-1mA, I_{B} =0	-32	-	-	V
Emitter-base breakdown voltage	BV_{EBO}	I_{c} =-50uA, I_{c} =0	-5	-	-	V
Collector cut-off current	I _{CBO}	V_{CB} =-20V, I_{E} =0	-	-	-1	μA
Emitter cut-off current	I _{EBO}	V_{EB} =-4V, I_C =0	-	-	-1	μA
DC current gain	h _{FE}	V_{CE} =-3V, I_{C} =-0.1A	120	-	320	-
Collector-emitter saturation voltage	V _{CE(sat)}	I _C =-2A, I _B =-200mA	-	-0.5	-0.8	V
Transition frequency	f⊤	V_{CE} =-5V, I _C =-500mA	-	150	-	MHz
Collector output capacitance	C _{ob}	V_{CB} =-10V, I_E =0, f=1MHz	-	50	-	pF

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Electrical Characteristic Curves

[TR1]



Electrical Characteristic Curves

[TR2]



Outline Dimension



SYMB⊡Ŀ					
	MINIMUM	NUMINAL	MAXIMUM		
A	1.245	-	1.445		
A1	0.125	0.175	0.275		
b	0.320	0.420	0.520		
С	0.170	0.220	0.270		
D	4.802	4.902	5.002		
E	5.870	6.020	6.170		
E1	3.761	3.861	3.961		
e					
L	0.462	0.562	0.662		
θ	0 *	_	8 *		

*Recommend PCB solder land [Unit: mm]



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